

2SJ652-RA11 Information



For Reference Only

Part Number 2SJ652-RA11

Manufacturer ON Semiconductor

Category Discrete Semiconductor Products

Transistors - FETs, MOSFETs - Single

Description MOSFET P-CH 60V 28A TO-220ML

Package TO-220-3 Full Pack

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









2SJ652-RA11 Specifications

Manufacturer Part Number	2SJ652-RA11
Manufacturer	ON Semiconductor
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-220-3 Full Pack
Series	-
FET Type	P-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	60V
Current - Continuous Drain (Id) @ 25°C	28A (Ta)
Drive Voltage (Max Rds On, Min Rds On)	4V, 10V
Vgs(th) (Max) @ Id	-
Gate Charge (Qg) (Max) @ Vgs	80nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	4360pF @ 20V
Vgs (Max)	±20V
FET Feature	-
Power Dissipation (Max)	-
Rds On (Max) @ Id, Vgs	38 mOhm @ 14A, 10V
Operating Temperature	150°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	TO-220ML
Package / Case	TO-220-3 Full Pack
	Report errors?

2SJ652-RA11 Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

2SJ652-RA11 Payment Methods



















2SJ652-RA11 Shipping Methods













If you have any question about 2SJ652-RA11, please do not hesitate to contact us!

Website: https://www.heisener.com E-mail: salesdept@heisener.com